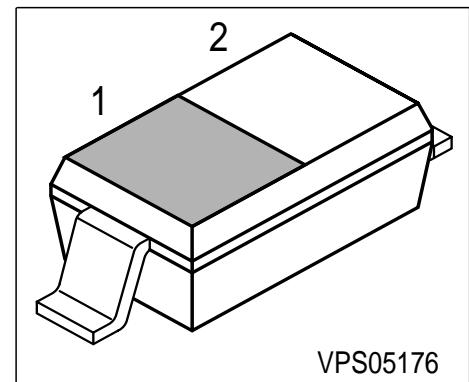


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## Silicon Tuning Diode

- Extended frequency range up to 2.5 GHz;  
special design for use in TV-sat indoor units
- High capacitance ratio



Type	Marking	Pin Configuration		Package
BB833	white X	1 = C	2 = A	SOD323

### Maximum Ratings

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_R$	30	V
Peak reverse voltage ( $R \geq 5k\Omega$ )	$V_{RM}$	35	
Forward current	$I_F$	20	mA
Operating temperature range	$T_{op}$	-55 ... 150	°C
Storage temperature	$T_{stg}$	-55 ... 150	

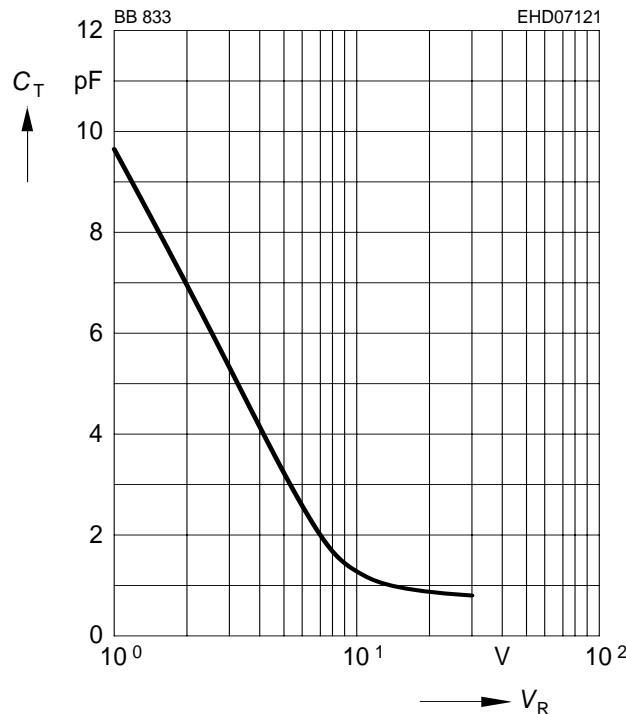
**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified.

<b>Parameter</b>	<b>Symbol</b>	<b>Values</b>			<b>Unit</b>
		<b>min.</b>	<b>typ.</b>	<b>max.</b>	
<b>DC characteristics</b>					
Reverse current $V_R = 30 \text{ V}$	$I_R$	-	-	20	nA
Reverse current $V_R = 30 \text{ V}, T_A = 85^\circ\text{C}$	$I_R$	-	-	500	
<b>AC characteristics</b>					
Diode capacitance $V_R = 1 \text{ V}, f = 1 \text{ MHz}$ $V_R = 28 \text{ V}, f = 1 \text{ MHz}$	$C_T$	8.5 0.6	9.3 0.75	10 0.9	pF
Capacitance ratio $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$	$C_{T1}/C_{T28}$	11	12.4	-	-
Capacitance matching $V_R = 1 \text{ V}, V_R = 28 \text{ V}, f = 1 \text{ MHz}$	$\Delta C_T/C_T$	-	-	3	%
Series resistance $V_R = 1 \text{ V}, f = 470 \text{ MHz}$	$r_s$	-	1.8	-	$\Omega$
Series inductance	$L_s$	-	1.8	-	nH

1) In-line matching. For details please refer to Application Note 047

**Diode capacitance**  $C_T = f(V_R)$

$f = 1\text{MHz}$



**Temperature coefficient of the diode capacitance**  $T_{CC} = f(V_R)$

$T_{CC}$  is plotted on a logarithmic scale from  $10^{-5}$  to  $10^{-3}$   $1/\text{ }^\circ\text{C}$ .

